

# Dimitrios Hariskos

## List of Publications by Year in descending order

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66  
papers

6,126  
citations

279487

23  
h-index

174990

52  
g-index

69  
all docs

69  
docs citations

69  
times ranked

4355  
citing authors

#	ARTICLE	IF	CITATIONS
1	New world record efficiency for Cu(In,Ga)Se <sub>2</sub> thin-film solar cells beyond 20%. Progress in Photovoltaics: Research and Applications, 2011, 19, 894-897.	4.4	1,888
2	Effects of heavy alkali elements in Cu(In,Ga)Se <sub>2</sub> solar cells with efficiencies up to 22.6%. Physica Status Solidi - Rapid Research Letters, 2016, 10, 583-586.	1.2	1,285
3	Properties of Cu(In,Ga)Se <sub>2</sub> solar cells with new record efficiencies up to 21.7%. Physica Status Solidi - Rapid Research Letters, 2015, 9, 28-31.	1.2	813
4	Compositional investigation of potassium doped Cu(In,Ga)Se <sub>2</sub> solar cells with efficiencies up to 20.8%. Physica Status Solidi - Rapid Research Letters, 2014, 8, 219-222.	1.2	483
5	Improved Photocurrent in Cu(In,Ga)Se <sub>2</sub> Solar Cells: From 20.8% to 21.7% Efficiency with CdS Buffer and 21.0% Cd-Free. IEEE Journal of Photovoltaics, 2015, 5, 1487-1491.	1.5	178
6	Gallium gradients in Cu(In,Ga)Se <sub>2</sub> thin-film solar cells. Progress in Photovoltaics: Research and Applications, 2015, 23, 717-733.	4.4	122
7	New reaction kinetics for a high-rate chemical bath deposition of the Zn(S,O) buffer layer for Cu(In,Ga)Se <sub>2</sub> -based solar cells. Progress in Photovoltaics: Research and Applications, 2012, 20, 534-542.	4.4	114
8	Heavy Alkali Treatment of Cu(In,Ga)Se <sub>2</sub> Solar Cells: Surface versus Bulk Effects. Advanced Energy Materials, 2020, 10, 1903752.	10.2	107
9	High-efficiency Cu(In,Ga)Se <sub>2</sub> cells and modules. Solar Energy Materials and Solar Cells, 2013, 119, 51-58.	3.0	106
10	Direct evidence for grain boundary passivation in Cu(In,Ga)Se <sub>2</sub> solar cells through alkali-fluoride post-deposition treatments. Nature Communications, 2019, 10, 3980.	5.8	95
11	Advances in Cost-Efficient Thin-Film Photovoltaics Based on Cu(In,Ga)Se <sub>2</sub> . Engineering, 2017, 3, 445-451.	3.2	79
12	High-efficiency Cu(In,Ga)Se <sub>2</sub> solar cells. Thin Solid Films, 2017, 633, 13-17.	0.8	58
13	Rubidium distribution at atomic scale in high efficient Cu(In,Ga)Se <sub>2</sub> thin-film solar cells. Applied Physics Letters, 2018, 112, .	1.5	57
14	CIGS Cells and Modules With High Efficiency on Glass and Flexible Substrates. IEEE Journal of Photovoltaics, 2014, 4, 440-446.	1.5	56
15	Substitution of the CdS buffer layer in CIGS thin-film solar cells. Vakuuum in Forschung Und Praxis, 2014, 26, 23-27.	0.0	55
16	Microscopic origins of performance losses in highly efficient Cu(In,Ga)Se <sub>2</sub> thin-film solar cells. Nature Communications, 2020, 11, 4189.	5.8	51
17	Quality and stability of compound indium sulphide as source material for buffer layers in Cu(In,Ga)Se <sub>2</sub> solar cells. Solar Energy Materials and Solar Cells, 2009, 93, 148-152.	3.0	50
18	Comparison of charge distributions in CIGS thin-film solar cells with ZnS/(Zn,Mg)O and CdS/i-ZnO buffers. Thin Solid Films, 2011, 519, 7549-7552.	0.8	47

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19	Influence of RbF post deposition treatment on heterojunction and grain boundaries in high efficient (21.1%) Cu(In,Ga)Se <sub>2</sub> solar cells. Nano Energy, 2019, 60, 103-110.	8.2	46
20	Chemical bath deposition of Zn(O,S) and CdS buffers: Influence of Cu(In,Ga)Se <sub>2</sub> grain orientation. Applied Physics Letters, 2013, 102, .	1.5	40
21	Method for a High-Rate Solution Deposition of Zn(O,S) Buffer Layer for High-Efficiency Cu(In,Ga)Se <sub>2</sub> -Based Solar Cells. IEEE Journal of Photovoltaics, 2016, 6, 1321-1326.	1.5	33
22	Impact of annealing on Cu(In,Ga)Se <sub>2</sub> solar cells with Zn(O,S)/(Zn,Mg)O buffers. Thin Solid Films, 2013, 535, 180-183.	0.8	30
23	Depth profiling with SNMS and SIMS of Zn(O,S) buffer layers for Cu(In,Ga)Se <sub>2</sub> thin-film solar cells. Surface and Interface Analysis, 2013, 45, 1811-1820.	0.8	26
24	Evidence for Chemical and Electronic Nonuniformities in the Formation of the Interface of RbF-Treated Cu(In,Ga)Se <sub>2</sub> with CdS. ACS Applied Materials & Interfaces, 2017, 9, 44173-44180.	4.0	25
25	Verification of phototransistor model for Cu(In,Ga)Se <sub>2</sub> solar cells. Thin Solid Films, 2015, 582, 392-396.	0.8	23
26	Rubidium Fluoride Post-Deposition Treatment: Impact on the Chemical Structure of the Cu(In,Ga)Se <sub>2</sub> Surface and CdS/Cu(In,Ga)Se <sub>2</sub> Interface in Thin-Film Solar Cells. ACS Applied Materials & Interfaces, 2018, 10, 37602-37608.	4.0	19
27	Valence band offsets at Cu(In,Ga)Se <sub>2</sub> /Zn(O,S) interfaces. Physica Status Solidi (A) Applications and Materials Science, 2014, 211, 1972-1980.	0.8	17
28	Impact of RbF-PDT on Cu(In,Ga)Se <sub>2</sub> solar cells with CdS and Zn(O,S) buffer layers. EPJ Photovoltaics, 2020, 11, 8.	0.8	17
29	Improved growth of solution-deposited thin films on polycrystalline Cu(In,Ga)Se <sub>2</sub> . Physica Status Solidi - Rapid Research Letters, 2016, 10, 300-304.	1.2	16
30	Accelerated Aging and Contact Degradation of CIGS Solar Cells. IEEE Journal of Photovoltaics, 2013, 3, 514-519.	1.5	15
31	A closer look at initial CdS growth on high-efficiency Cu(In, Ga)Se <sub>2</sub> absorbers using surface-sensitive methods. , 2016, , .		14
32	UV-Selective Optically Transparent Zn(O,S)-Based Solar Cells. Solar Rrl, 2020, 4, 2000470.	3.1	12
33	Influence of Substrate Temperature during In <sub>x</sub> S <sub>y</sub> Sputtering on Cu(In,Ga)Se <sub>2</sub> /Buffer Interface Properties and Solar Cell Performance. Applied Sciences (Switzerland), 2020, 10, 1052.	1.3	12
34	Electrostatic potential fluctuations and light-soaking effects in Cu(In,Ga)Se <sub>2</sub> solar cells. Progress in Photovoltaics: Research and Applications, 2020, 28, 919-934.	4.4	11
35	Improved photocurrent in Cu(In,Ga)Se <sub>2</sub> solar cells: From 20.8% to 21.7% efficiency. , 2015, , .		10
36	Thermodynamic limitations for alkali metals in Cu(In,Ga)Se <sub>2</sub> . Journal of Materials Research, 2017, 32, 3789-3800.	1.2	10

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37	Resonant Raman scattering based approaches for the quantitative assessment of nanometric ZnMgO layers in high efficiency chalcogenide solar cells. <i>Scientific Reports</i> , 2017, 7, 1144.	1.6	9
38	Effects of Sputtered $\text{In}_x\text{S}_y$ Buffer on CIGS with RbF Post-Deposition Treatment. <i>ECS Journal of Solid State Science and Technology</i> , 2021, 10, 055006.	0.9	8
39	Photo-assisted electrodeposition of a ZnO front contact on a p/n junction. <i>Electrochimica Acta</i> , 2016, 220, 176-183.	2.6	6
40	Near-Surface $[\text{Ga}/([\text{In}]+[\text{Ga}])]$ Composition in $\text{Cu}(\text{In,Ga})\text{Se}_2$ Thin-Film Solar Cell Absorbers: An Overlooked Material Feature. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2019, 216, 1800856.	0.8	6
41	Giant Voc Boost of Low-Temperature Annealed $\text{Cu}(\text{In,Ga})\text{Se}_2$ with Sputtered Zn(O,S) Buffers. <i>Physica Status Solidi - Rapid Research Letters</i> , 2019, 13, 1900145.	1.2	6
42	Structural and microchemical characterization of $\text{Cu}(\text{In,Ga})\text{Se}_2$ solar cells with solution-grown CdS, Zn(O,S), and $\text{In}_x(\text{O,S})_y$ buffers. <i>Thin Solid Films</i> , 2019, 671, 133-138.	0.8	6
43	Evaluation of defect formation in chalcopyrite compounds under Cu-poor conditions by advanced structural and vibrational analyses. <i>Acta Materialia</i> , 2022, 223, 117507.	3.8	5
44	Effects of material properties of band-gap-graded $\text{Cu}(\text{In,Ga})\text{Se}_2$ thin films on the onset of the quantum efficiency spectra of corresponding solar cells. <i>Progress in Photovoltaics: Research and Applications</i> , 2022, 30, 1238-1246.	4.4	5
45	Influence of sputtered gallium oxide as buffer or high-resistive layer on performance of $\text{Cu}(\text{In,Ga})\text{Se}_2$ -based solar cells. <i>Journal of Materials Research</i> , 2022, 37, 1825-1834.	1.2	5
46	Short-circuit current improvement of $\text{CuGaSe}_2$ solar cells with a ZnS/(Zn,Mg)O buffer combination. <i>Physica Status Solidi - Rapid Research Letters</i> , 2008, 2, 80-82.	1.2	4
47	Characterization of solution-grown and sputtered $\text{In}_x(\text{O,S})_y$ buffer layers in $\text{Cu}(\text{In,Ga})\text{Se}_2$ solar cells by analytical TEM. <i>Semiconductor Science and Technology</i> , 2020, 35, 034001.	1.0	4
48	The Application of Sputtered Gallium Oxide as Buffer for $\text{Cu}(\text{In,Ga})\text{Se}_2$ Solar Cells. <i>Physica Status Solidi - Rapid Research Letters</i> , 2021, 15, 2100180.	1.2	4
49	Using the inelastic background in hard x-ray photoelectron spectroscopy for a depth-resolved analysis of the CdS/ $\text{Cu}(\text{In,Ga})\text{Se}_2$ interface. <i>Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films</i> , 2021, 39, .	0.9	4
50	Photoluminescence studies of polycrystalline $\text{Cu}(\text{In,Ga})\text{Se}_2$ : Lateral inhomogeneities beyond Abbe's diffraction limit. <i>Journal of Applied Physics</i> , 2015, 118, .	1.1	3
51	IZO or IOH Window Layers Combined with Zn(O,S) and CdS Buffers for $\text{Cu}(\text{In,Ga})\text{Se}_2$ Solar Cells. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2017, 214, 1700688.	0.8	3
52	Accelerated aging and contact degradation of CIGS solar cells. , 2012, , .		2
53	Long term endurance test and contact degradation of CIGS solar cells. , 2013, , .		2
54	Electrodeposition of ZnO-doped films as window layer for Cd-free CIGS-based solar cells. , 2016, , .		2

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55	Averaged angle-resolved electroreflectance spectroscopy on Cu(In,Ga)Se <sub>2</sub> solar cells: Determination of buffer bandgap energy and identification of secondary phase. Applied Physics Letters, 2019, 115, .	1.5	2
56	Influence of Cu(In,Ga)Se <sub>2</sub> grain orientation on solution growth of Zn(O,S) and CdS. , 2012, , .		1
57	Fluctuations in net doping and lifetime in Cu(In,Ga)Se <sub>2</sub> solar cells. , 2018, , .		1
58	Numerical simulation of CIGS solar cells with Zn(O,S) or (Cd,Zn)S buffers and (Zn,Mg)O as high-resistive layer. , 2019, , .		1
59	Deuterium Markers in CdS and Zn(O,S) Buffer Layers Deposited by Solution Growth for Cu(In,Ga)Se <sub>2</sub> Thin-Film Solar Cells. Physica Status Solidi - Rapid Research Letters, 2017, 11, 1700288.	1.2	0
60	Increased and FF in ZnO <sub>1-x</sub> S <sub>x</sub> -buffered CuIn <sub>1-x</sub> Ga <sub>x</sub> Se <sub>2</sub> Solar Cells by Cadmium Partial Electrolyte Treatment. , 2017, , .		0
61	Notice of Removal Method for a high-rate solution deposition of Zn(O,S) buffer layer for high efficiency Cu(In,Ga)Se <sub>2</sub> -based solar cells. , 2017, , .		0
62	Microscopic materials properties of a high-efficiency Cu(In,Ga)Se <sub>2</sub> solar cell - a case study. , 2018, , .		0
63	Electroreflectance spectroscopy on CdS and Zn(O,S) buffer layers in Cu(In,Ga)Se <sub>2</sub> solar cells: Suppression of interference effects. , 2018, , .		0
64	Modification of electronic grain boundary properties of Cu(In, Ga)Se <sub>2</sub> by alkali-fluoride post deposition treatments. , 2018, , .		0
65	Electroreflectance studies of Zn(O,S) buffer layers in Cu(In,Ga)Se <sub>2</sub> solar cells: Bandgap energies and secondary phases. , 2019, , .		0
66	Correlative APT/EBIC investigations of sputtered In-based and Zn(O,S) buffers for CIGS solar cells. , 2020, , .		0